

Darlington Transistor TO-3

multicomp PRO



Description:

Darlington complementary silicon power transistors. Designed for general-purpose amplifier and low frequency switching applications.

Features:

- High DC current gain - $h_{FE} = 3,500$ (typical) at $I_C = 5\text{ A DC}$
- Collector-emitter sustaining voltage - at 100mA
 $V_{CEO}(\text{sus}) = 80\text{ V DC (min.)}$ - 2N6058
- Monolithic construction with built-in-base-emitter shunt resistors

Maximum Ratings

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	80	V DC
Collector-Base Voltage	V_{CB}		
Emitter-Base Voltage	V_{EB}		
Collector Current -Continuous -Peak	I_C	12 20	A DC
Base Current	I_B	0.2	
Total Power Dissipation at $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	150 0.857	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{Stg}	-65 $^\circ\text{C}$ to +200 $^\circ\text{C}$	$^\circ\text{C}$

Thermal Characteristics

Characteristic	Symbol	Max.	Unit
Thermal Resistance Junction to Case	$R_{\theta_{JC}}$	1.17	$^\circ\text{C/W}$

(1) Indicates JEDEC Registered Data.

Darlington Transistor

TO-3

multicomp PRO

Electrical Characteristics (TC = 25°C unless otherwise noted)

Characteristic	Symbol	Min.	Max.	Unit
Off Characteristics				
Collector-Emitter Sustaining Voltage (2) (IC = 100mA DC, IB = 0)	VCEO (sus)	80	-	V DC
Collector Cut off Current (VCE = 40V DC, IB = 0)	ICEO	-	1	
Collector Cut off Current (VCE = Rated VCEO, VBE (off) = 1.5V DC) (VCE = Rated VCEO, VBE (off) = 1.5V DC, TC = 150°C)	ICEX	-	0.5 5	mA DC
Emitter Cut off Current (VBE = 5V DC, IC = 0)	IEBO	-	2	

On Characteristics (2)

DC Current Gain (IC = 6A DC, VCE = 3V DC) (IC = 12A DC, VCE = 3V DC)	hFE	750 100	18,000 -	-
Collector-Emitter Saturation Voltage (IC = 6A DC, IB = 24mA DC) (IC = 12A DC, IB = 120mA DC)	VCE (sat)	- -	2 3	
Base-Emitter Saturation Voltage (IC = 12A DC, IB = 120mA DC)	VBE (sat)	-	4	V DC
Base-Emitter On Voltage (IC = 6A DC, VCE = 3V DC)	VBE (on)	-	2.8	

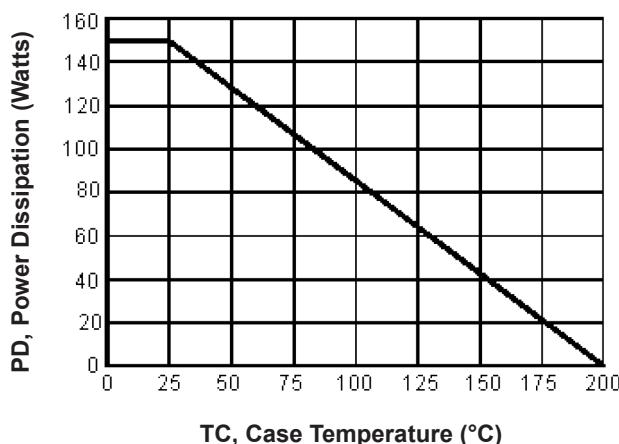
Dynamic Characteristics

Magnitude of Common-Emitter Small-Signal Short-Circuit Forward Current Transfer Ratio (IC = 5A DC, VCE = 3V DC, f = 1MHz)	hfe	4	-	MHz
Output Capacitance (VCB = 10V DC, IE = 0, f = 0.1MHz)	Cob	-	500 300	pF
Small-Signal Current Gain (IC = 5A DC, VCE = 3V DC, f = 1kHz)	hfe	300	-	-

Indicates JEDEC Registered Data.

(2) Pulse test: Pulse Width = 300μs, Duty Cycle = 2%.

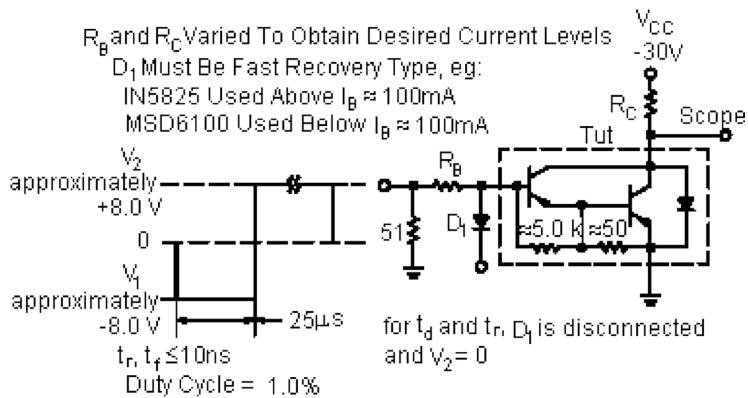
Power Derating



Darlington Transistor TO-3

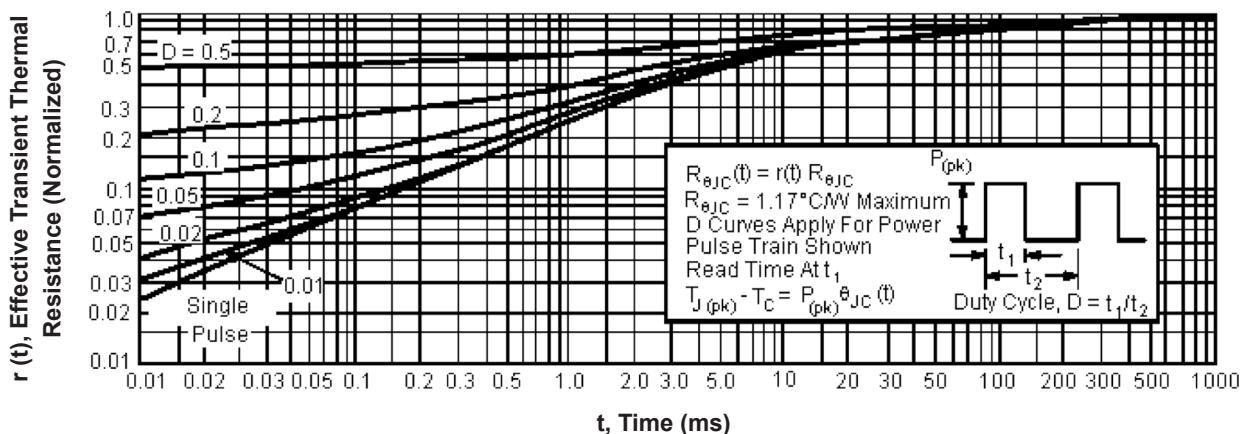
multicomp PRO

Switching Times Test Circuit

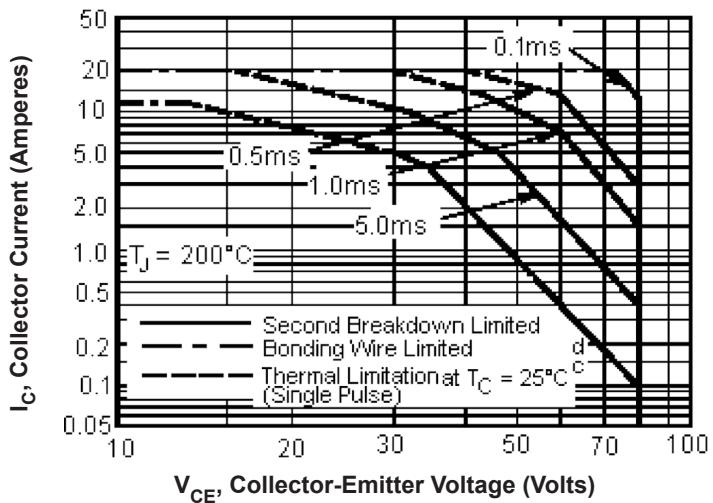


For NPN Test Circuit Reverse Diode and Voltage Polarities

Thermal Response



Active-Region Safe Operating Area



There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

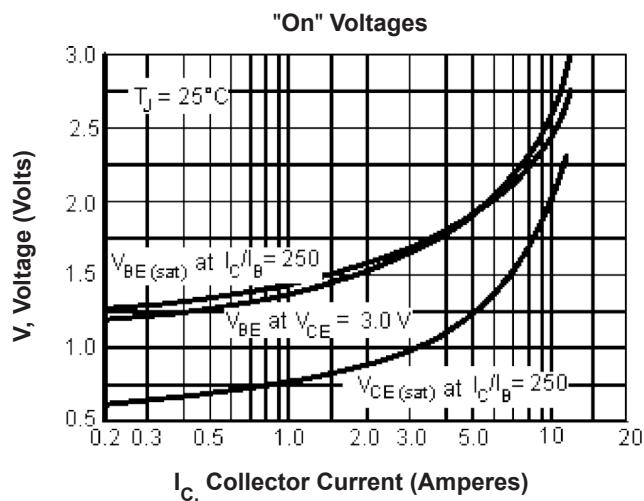
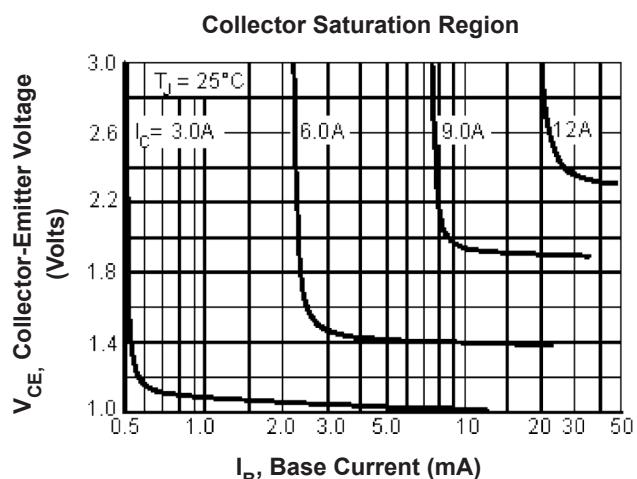
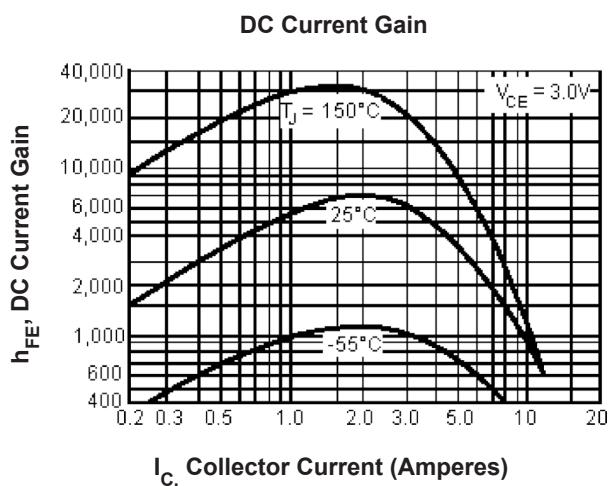
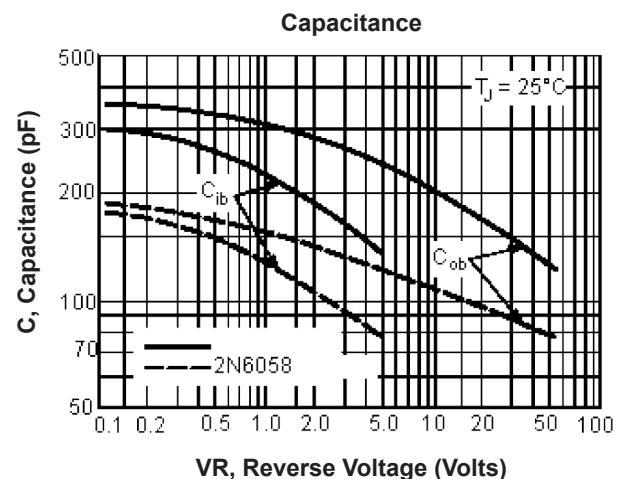
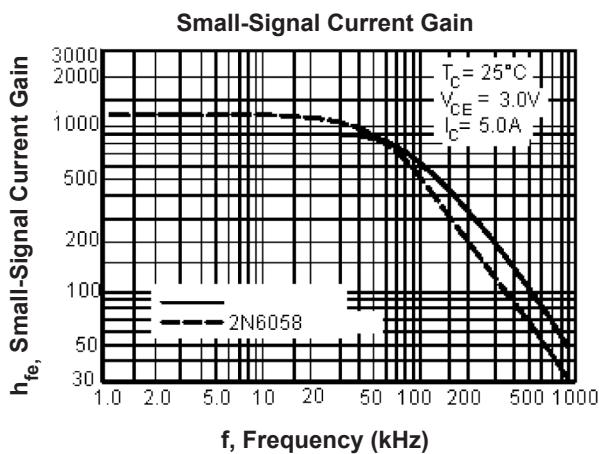
The data is based on T_{J(pk)} = 200°C; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty

cycles to 10% provided T_{J(pk)} ≤ 200°C; T_{J(pk)} may be calculated from the data. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

Darlington Transistor

TO-3

multicomp PRO

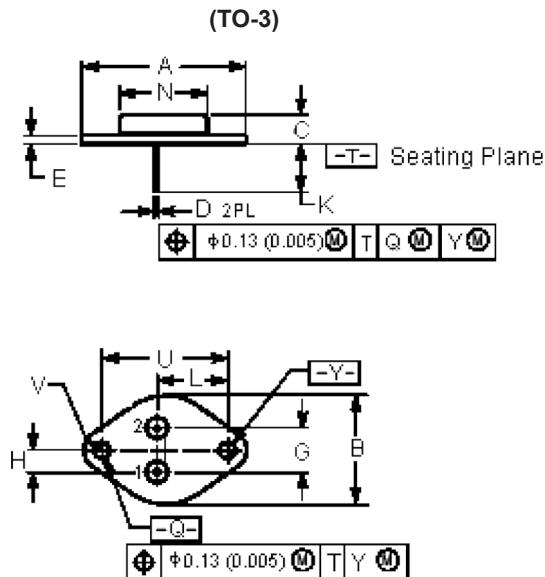


Darlington Transistor

TO-3

multicomp PRO

Dimensions



Dimensions	Min.	Max.
A	1.55 (39.37) Reference	
B	-	1.05 (26.67)
C	0.25 (6.35)	0.335 (8.51)
D	0.038 (0.97)	0.043 (1.09)
E	0.055 (1.4)	0.07 (1.77)
G	0.43 (10.92) BSC	
H	0.215 (5.46) BSC	
K	0.44 (11.18)	0.48 (12.19)
L	0.665 (16.89) BSC	
N	-	0.83 (21.08)
Q	0.151 (3.84)	0.165 (4.19)
U	1.187 (30.15) BSC	
V	0.131 (3.33)	0.188 (4.77)

Dimensions : Inches (Millimetres)

Pin Configuration:

1. Base
2. Emitter
- Collector (Case)

Part Number Table

Description	Part Number
Darlington Transistor, TO-3	2N6058

Important Notice : This data sheet and its contents (the "Information") belong to the members of the AVNET group of companies (the "Group") or are licensed to it. No licence is granted for the use of it other than for information purposes in connection with the products to which it relates. No licence of any intellectual property rights is granted. The Information is subject to change without notice and replaces all data sheets previously supplied. The Information supplied is believed to be accurate but the Group assumes no responsibility for its accuracy or completeness, any error in or omission from it or for any use made of it. Users of this data sheet should check for themselves the Information and the suitability of the products for their purpose and not make any assumptions based on information included or omitted. Liability for loss or damage resulting from any reliance on the Information or use of it (including liability resulting from negligence or where the Group was aware of the possibility of such loss or damage arising) is excluded. This will not operate to limit or restrict the Group's liability for death or personal injury resulting from its negligence. Multicomp Pro is the registered trademark of Premier Farnell Limited 2019.